

### NOT RECOMMENDED FOR NEW DESIGN **USE DMN2056U**



**DMN2075U** 

### N-CHANNEL ENHANCEMENT MODE MOSFET

#### **Features**

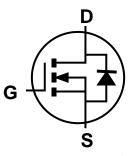
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

## **Mechanical Data**

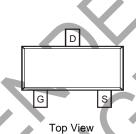
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Terminals Connections: See Diagram Below
- Weight: 0.008 grams (Approximate)











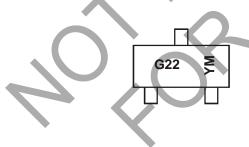
### **Ordering Information** (Note 4)

			_	
Part Number		Case	П	Packaging
DMN2075U-7		SOT23	7	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
  2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



G22 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: E = 2017) M = Month (ex: 9 = September)

#### Date Code Key

Year	2009	,		2017	2018	2019	2020	2021	202	22 2	023	2024	2025
Code	W	,		Е	F	G	Н	1	J		K	L	М
Mont	h	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	е	1	2	3	4	5	6	7	8	9	0	N	D



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# **Maximum Ratings** ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characte	eristic		Symbol	Value	Unit
Drain-Source Voltage		V <sub>DSS</sub>	20	V	
Gate-Source Voltage		V <sub>GSS</sub>	±8	V	
Continuous Drain Current (Note 5)	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	4.2 3.4	А
Maximum Continuous Body Diode For	ote 6)	Is	1.2	А	
Pulsed Drain Current (Note 6)			I <sub>DM</sub>	27	Α
Pulsed Body Diode Forward Current (N	lote 6)		I <sub>SM</sub>	24	А

# **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P <sub>D</sub>	0.8	W
Thermal Resistance, Junction to Ambient @T <sub>A</sub> = +25°C	$R_{\theta JA}$	156	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes:

- 5. Device mounted on FR-4 PCB, with minimum recommended pad layout.
- 6. Repetitive rating, pulse width limited by junction temperature.

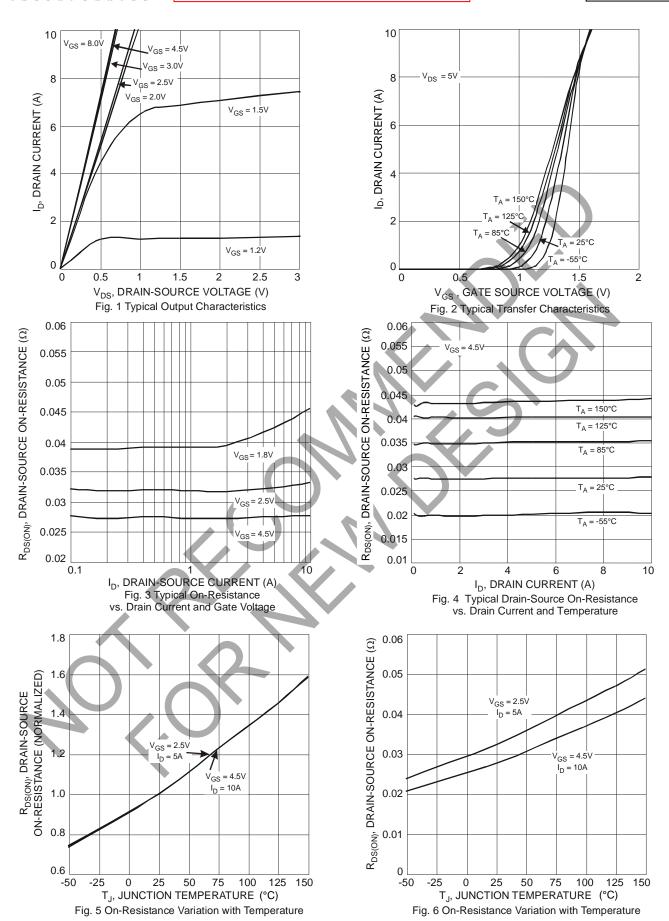
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)			4			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	20	_		V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	I <sub>DSS</sub>			100	_ nA	$V_{DS} = 16V, V_{GS} = 0V$
Gate-Source Leakage	I <sub>GSS</sub>	<b>—</b>		±100	nA	$V_{GS} = \pm 8V$ , $V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	0.4		1.0	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>		25 30	38 45	mΩ	$V_{GS} = 4.5V, I_D = 3.6A$ $V_{GS} = 2.5V, I_D = 3.1A$
Forward Transfer Admittance	Y <sub>FS</sub>	1-1	13	_	S	$V_{DS} = 5V, I_D = 3.6A$
Diode Forward Voltage	VsD	-	0.75	1.0	V	$V_{GS} = 0V, I_{S} = 1A$
DYNAMIC CHARACTERISTICS (Note 8)						•
Input Capacitance	C <sub>ISS</sub>	_	594.3	_	pF	101/11/
Output Capacitance	Coss	_	64.5	_	pF	$V_{DS} = 10V, V_{GS} = 0V,$ f = 1.0MHz
Reverse Transfer Capacitance	C <sub>RSS</sub>	_	57.7	_	pF	1 = 1.000112
Gate Resistance	$R_g$	_	1.5	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$
Total Gate Charge	$Q_{G}$	_	7.0	_	nC	1 5 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1
Gate-Source Charge	Q <sub>GS</sub>	_	0.9	_	nC	$V_{GS} = 4.5V, V_{DS} = 10V,$ $I_{D} = 3.6A$
Gate-Drain Charge	$Q_{GD}$	_	1.4	_	nC	1D = 3.6A
Turn-On Delay Time	t <sub>D(ON)</sub>	_	7.4	_	ns	
Turn-On Rise Time	t <sub>R</sub>		9.8	_	ns	$V_{DD} = 10V, V_{GS} = 4.5V,$
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	28.1	_	ns	$R_L = 2.78\Omega, R_g = 1.0\Omega$
Turn-Off Fall Time	$t_F$		6.7	_	ns	

Notes:

- 7. Short duration pulse test used to minimize self-heating effect.8. Guaranteed by design. Not subject to production testing.





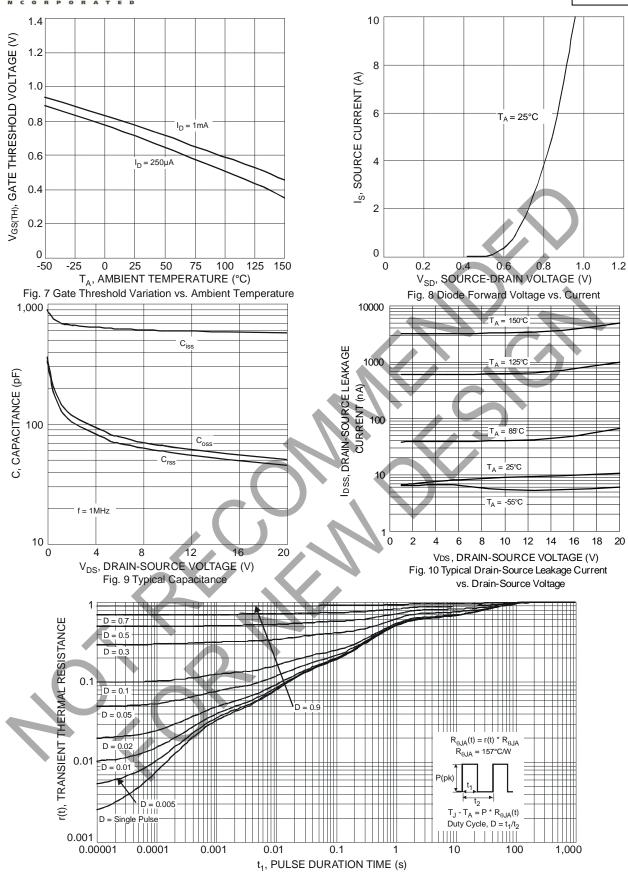
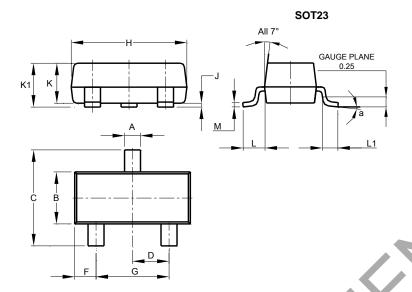


Fig. 11 Transient Thermal Response



# **Package Outline Dimensions**

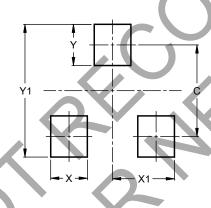
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
C	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
٦	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а	0°	8°	<b>-</b> -				
All Dimensions in mm							

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
V4	2.0

SOT23



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**DMN2075U** 

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